NSN 5962-01-248-8649

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and electrostatic sensitive and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
90.00 nanoseconds access
Memory Device Type:
Prom
Memory Capacity:
1024k x 8
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
24 printed circuit
Specification Data:
81349-mil-m-81349/209 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0